

# P32LF10SLK

## Power MOSFETs

100V, 32A, N-channel

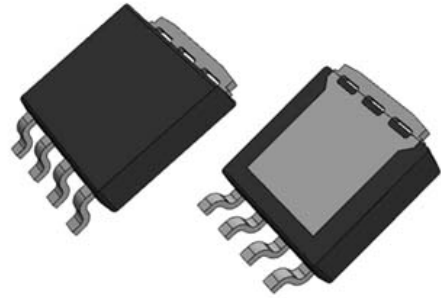
### Feature

- N-channel
- Small SMD
- Large Current
- Low Ron
- 4.5V Gate Drive
- Low Capacitance
- Based on AEC-Q101
- Halogen free
- Pb free terminal
- RoHS:Yes

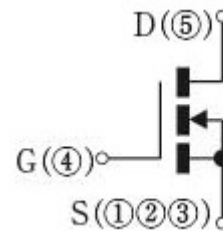
### OUTLINE

Package (House Name): LF

Package (JEDEC Code): MO-235B similar



### Equivalent circuit



### Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage temperature	Tstg		-55 to 175	°C
Channel temperature	Tch		-55 to 175	°C
Drain-source voltage	V <sub>DSS</sub>		100	V
Gate-source voltage	V <sub>GSS</sub>		±20	V
Continuous drain current(DC)	I <sub>D</sub>		32	A
Continuous drain current(Peak)	I <sub>DP</sub>	Pulse width 10μs, duty=1/100	96	A
Total power dissipation	P <sub>T</sub>		168	W
Single avalanche current	I <sub>AS</sub>	Starting Tch=25°C Tch≤150°C	25	A
Single avalanche energy	E <sub>AS</sub>	Starting Tch=25°C Tch≤150°C	69	mJ

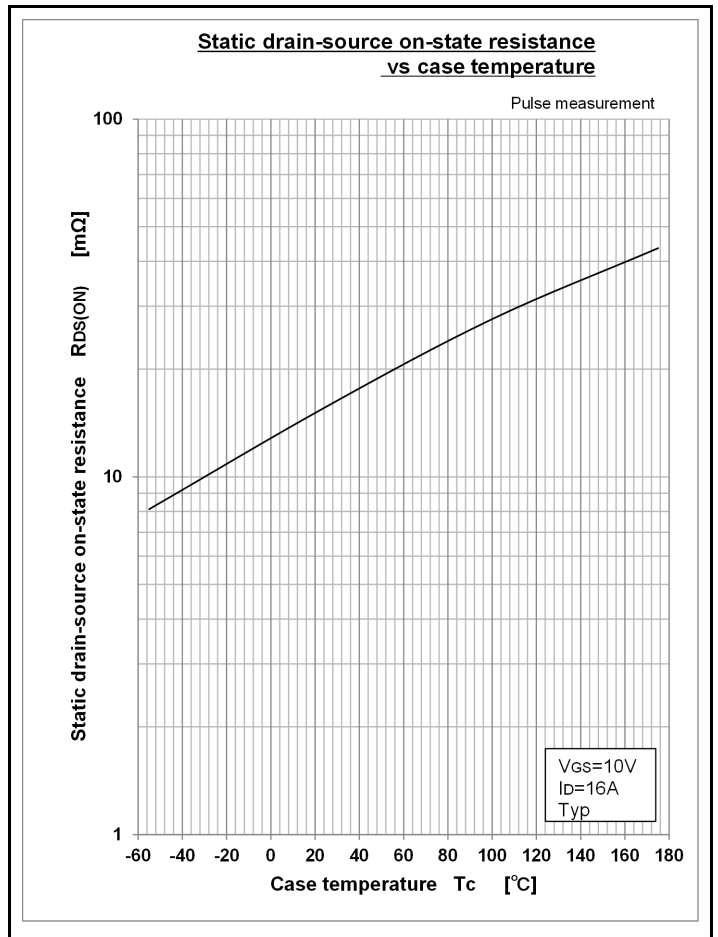
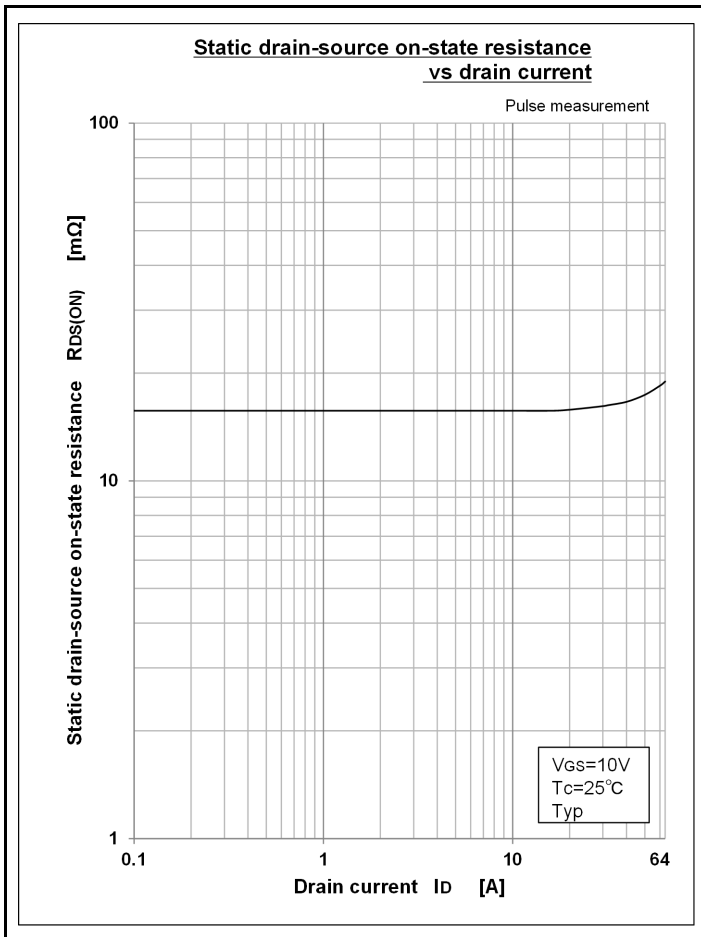
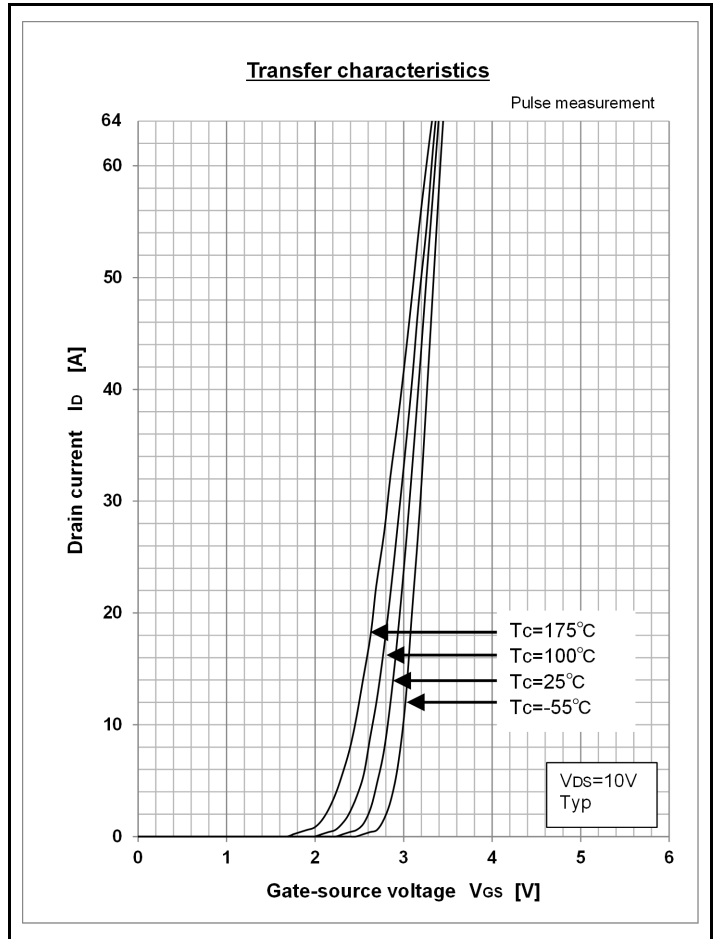
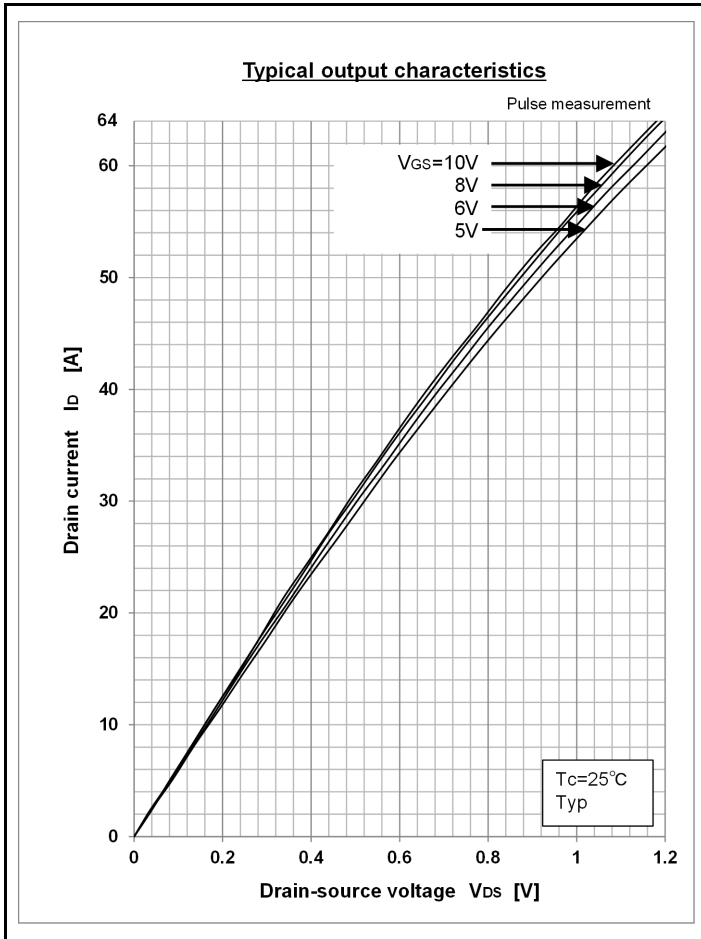
\* : See the original Specifications

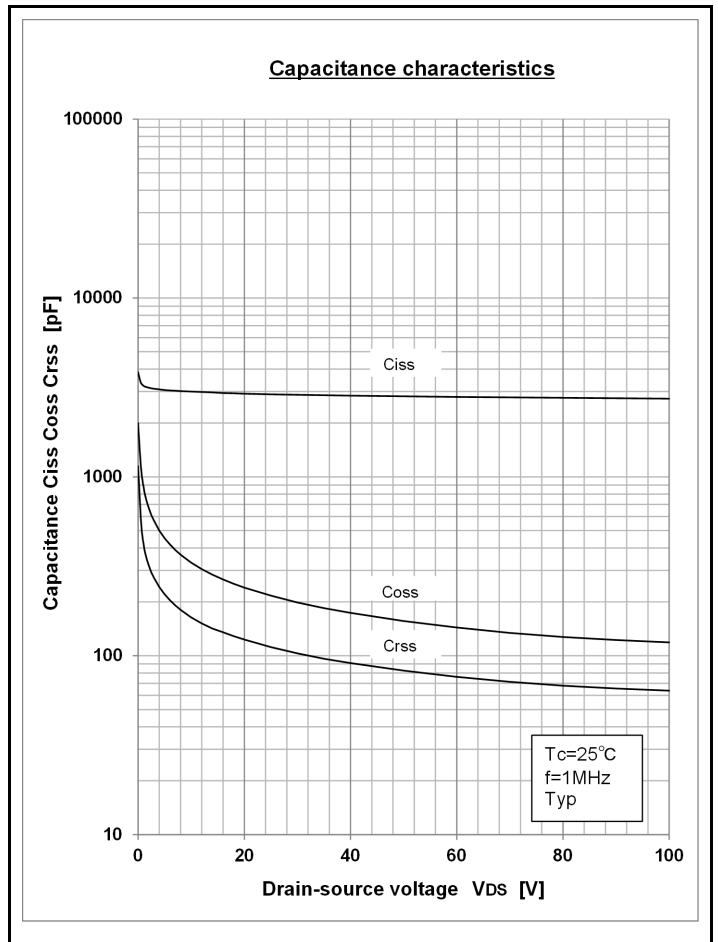
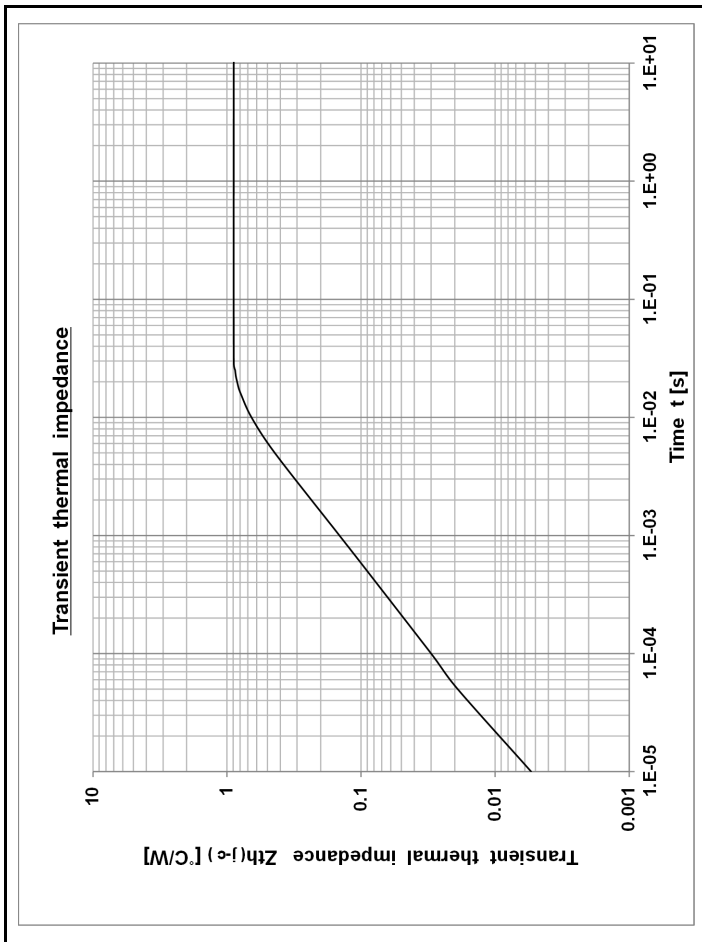
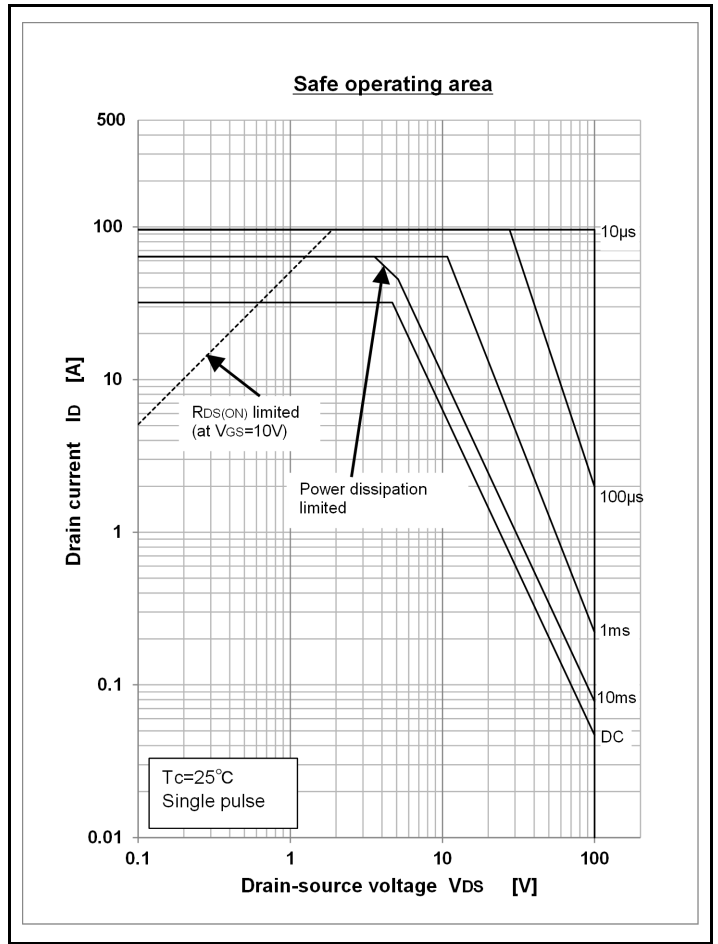
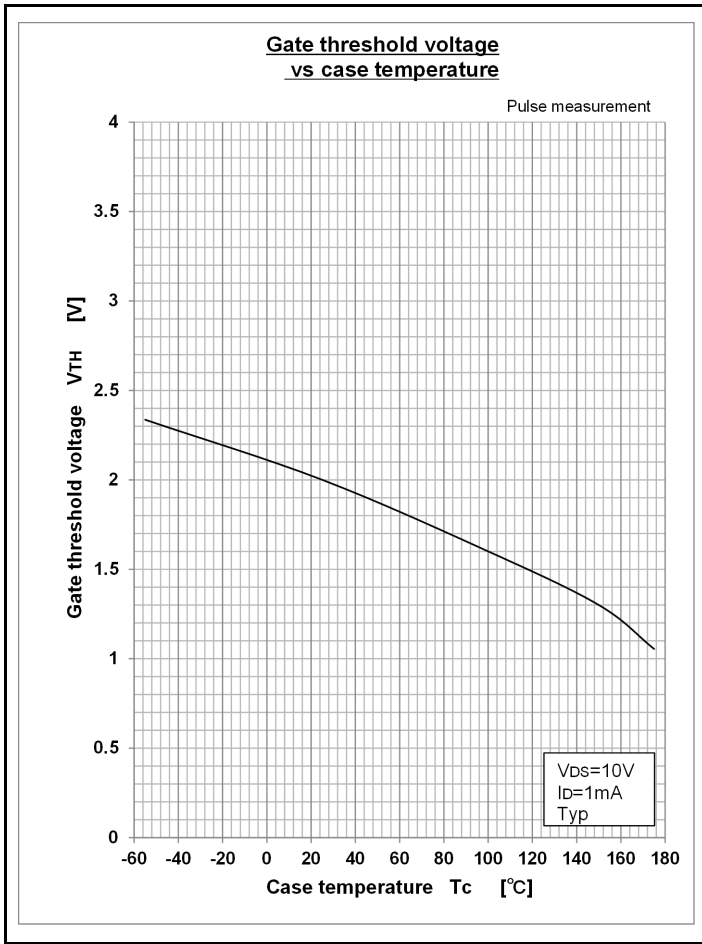
**Electrical Characteristics** (unless otherwise specified : Tc=25°C)

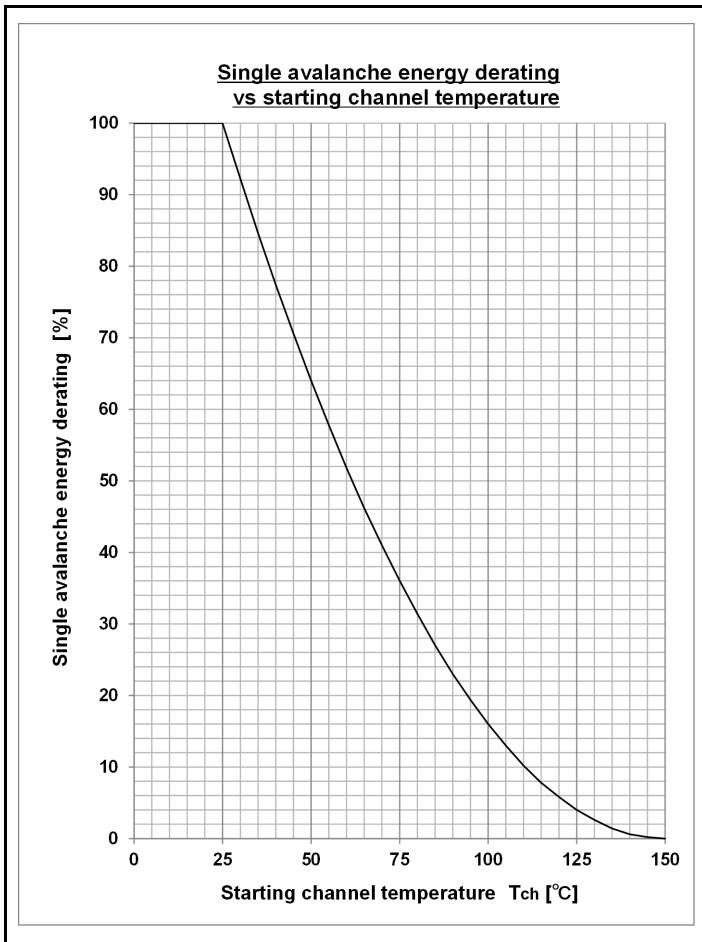
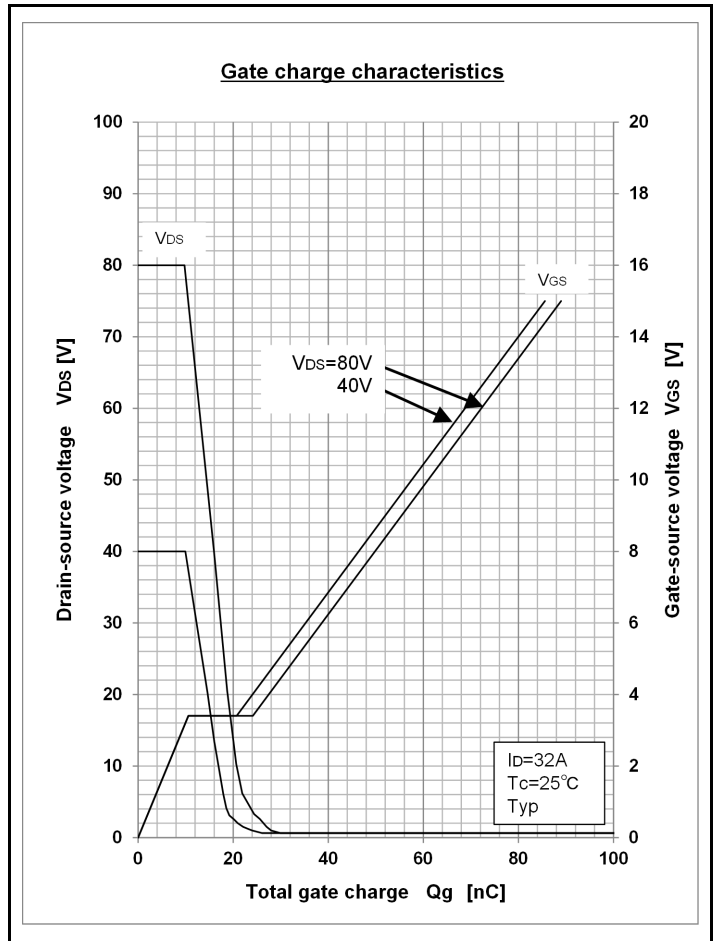
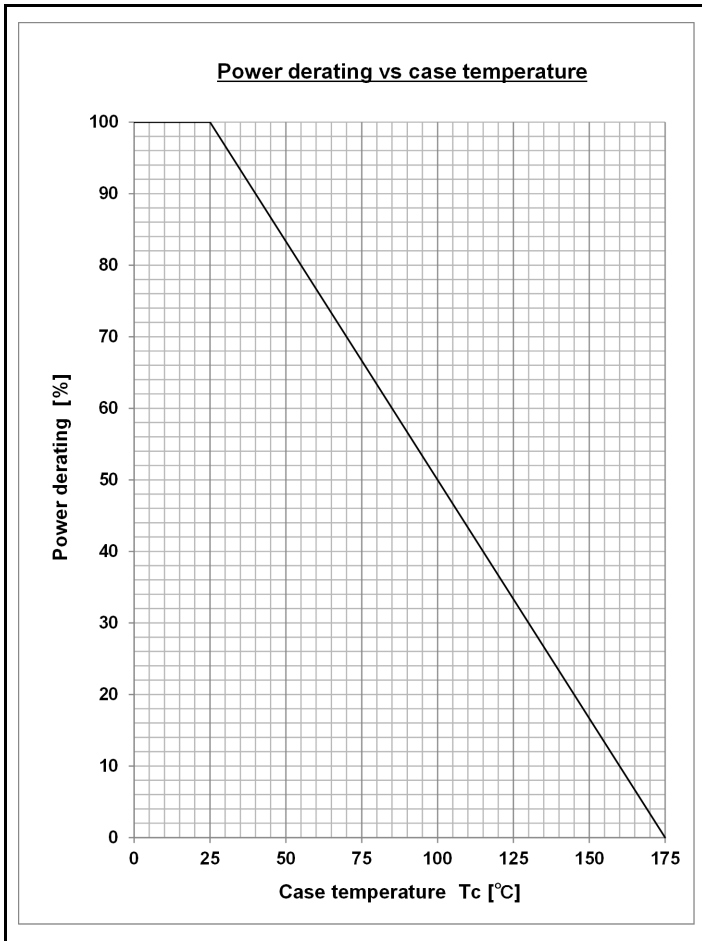
Item	Symbol	Conditions	Ratings			Unit
			MIN	TYP	MAX	
Drain-Source breakdown voltage	$V_{(BR)DSS}$	ID=1mA, VGS=0V	100			V
Zero gate voltage drain current	$I_{DSS}$	VDS=100V, VGS=0V			1	μA
Gate-source leakage current	$I_{GSS}$	VGS=±20V, VDS=0V			±0.1	μA
Forward transconductance	$g_{fs}$	ID=16A, VDS=10V	10			S
Static drain-source on-state resistance	$R_{DS(ON)}$	ID=16A, VGS=10V		0.0157	0.0197	Ω
Static drain-source on-state resistance	$R_{DS(ON)}$	ID=16A, VGS=4.5V		0.0171	0.023	Ω
Gate threshold voltage	$V_{th}$	ID=1mA, VDS=10V	1.5	2	2.5	V
Source-drain diode forward voltage	$V_{SD}$	IS=32A, VGS=0V			1.5	V
Thermal resistance	$R_{th(j-c)}$	Junction to case, with heatsink			0.89	°C/W
Total gate charge	$Q_g$	VDD=80V, VGS=10V, ID=32A		61		nC
Gate to source charge	$Q_{gs}$	VDD=80V, VGS=10V, ID=32A		11		nC
Gate to drain charge	$Q_{gd}$	VDD=80V, VGS=10V, ID=32A		16		nC
Input capacitance	$C_{iss}$	VDS=25V, VGS=0V, f=1MHz		2890		pF
Reverse transfer capacitance	$C_{rss}$	VDS=25V, VGS=0V, f=1MHz		110		pF
Output capacitance	$C_{oss}$	VDS=25V, VGS=0V, f=1MHz		216		pF
Turn-on delay time	$t_{d(on)}$	ID=16A, RL=3.13Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		4.7		ns
Rise time	$t_r$	ID=16A, RL=3.13Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		9		ns
Turn-off delay time	$t_{d(off)}$	ID=16A, RL=3.13Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		49		ns
Fall time	$t_f$	ID=16A, RL=3.13Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		20		ns
Diode reverse recovery time	$t_{rr}$	IF=32A, VGS=0V, di/dt=100A/μs		54		ns
Diode reverse recovery charge	$Q_{rr}$	IF=32A, VGS=0V, di/dt=100A/μs		105		nC

\* : See the original Specifications

# CHARACTERISTIC DIAGRAMS

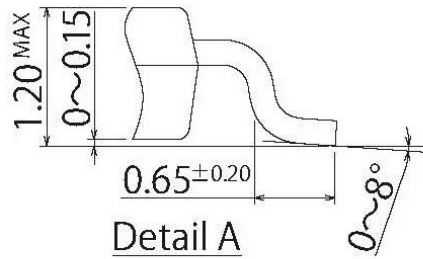
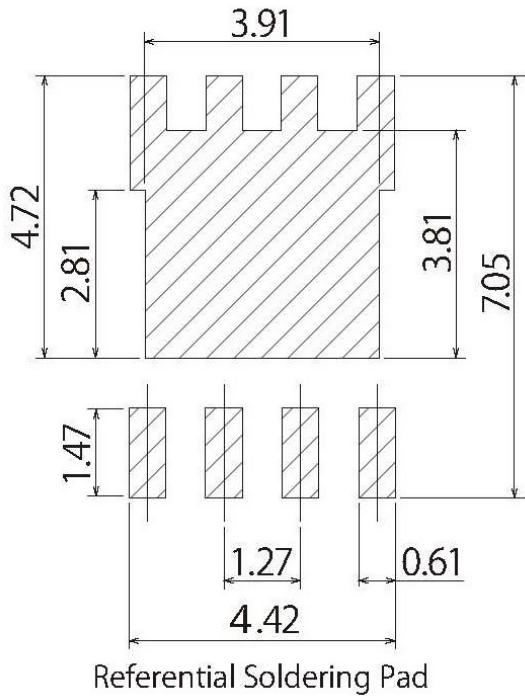
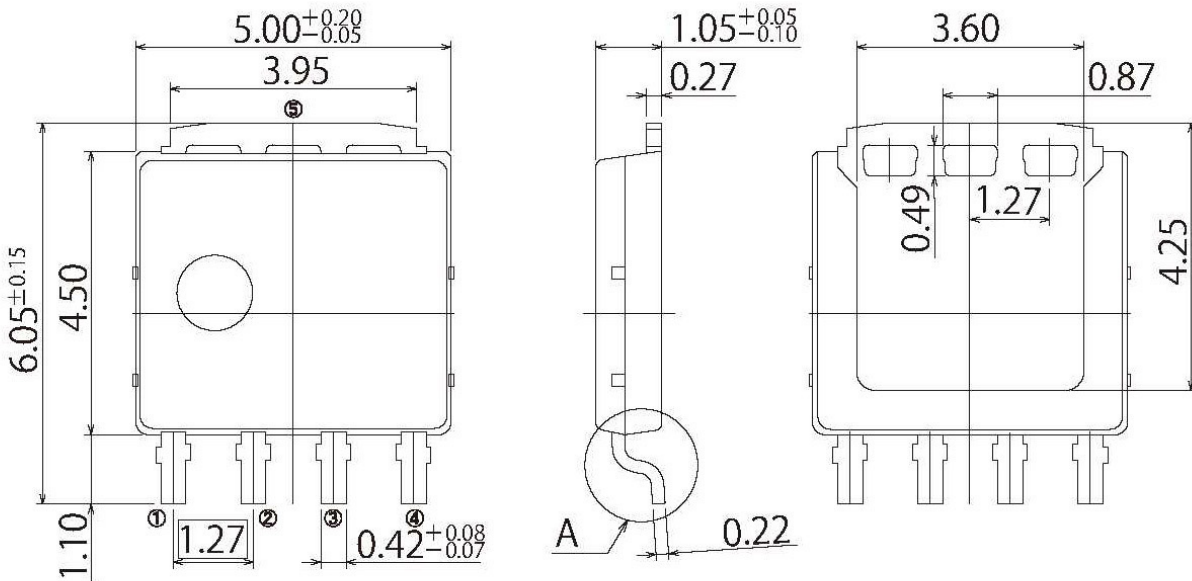






G7

JEDEC Code	MO-235B similar
JEITA Code	—
House Name	LF



• Optimize soldering pad to the board design and soldering condition.

## Notes

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